

05.06.2014

EYP-BAL-0980-18000-4020-CDL02-0000

BROAD AREA LASER

GaAs Semiconductor Laser Diode Single Emitter Structure



Revision 0.91







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General Product Information

Product	Application
980 nm Broad Area Laser	Medical
with Collimating Double Lens	Material Processing
Thermistor	



Absolute Maximum Ratings

Symbol	Unit	min	typ	max
T_S	°C	-20		70
T_{C}	°C	5		40
I _F	А			24
V_R	V			2
P_{opt}	W			19
	T _S T _C I _F V _R	T _S °C T _C °C I _F A V _R V	T_S °C -20 T_C °C 5 I_F A V_R V	T_{S} °C -20 T_{C} °C 5 I_{F} A V_{R} V

non condensing non condensing Stress in excess of one of the Absolute Maximum Ratings can cause permanent damage to the device.

Recommended Operational Conditions

0.0			
· C	15		30
I _F A			23
opt W			18
	F A W	F A W	F A

Measurement Conditions / Comments
non condensing

Characteristics at T_{LD} = 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	965	980	995
Spectral Width (FWHM)	$\Delta\lambda$	nm		3	
Temperature Coefficient of Wavelength	$d\lambda$ / dT	nm / K		0.4	
Output Power @ I _F - 23 A	P _{opt}	W	18		
Slope Efficiency	η_{d}	W/A	0.7	1.0	
Threshold Current	I_{th}	А		2.0	2.5
Voltage at Threshold	U_{th}	V	1.2		
Operational Current @ $P_{opt} = 18 W$	l _{op}	А			23
Operational Voltage	U_op	V	1.5	1.9	2.1

Measurement Conditions / Comments						
$P_{opt} = 18 W$						
total output measured with integrating sphere						
$I_{\text{F}} = P_{\text{opt}}$						
$P_{opt} = 18 \text{ W}$						
opt — 10 vv						



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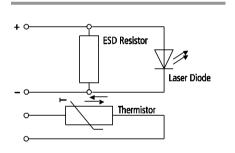
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Characteristics at T _{amb} 25 °C at Begin Of Life						
Parameter	Symbol	Unit	min	typ	max	
Differential Serial Resistance	R_{S}	mΩ	20	40	60	
Stripe Width	W_s	μm		200		
Cavity Length	L	μm		4000		
Divergence parallel	$\Theta_{ }$	0	1.0	1.5	2.0	
Divergence perpendicular	Θ_{\perp}	o	0.4	0.6	0.8	
Beam Width parallel	S	mm	2	3	4	
Beam Width perpendicular	F_{\perp}	mm	0.2	0.4	0.6	
Spectral Mode (longitudinal)				Multi Mod	le	
Polarization				TE		

Measurement Conditions / Comments
Second Moment Full Angle
Second Moment Full Angle
Delayingtion payallal to base plate
Polarization parallel to base plate

ESD-Resistor

Parameter	Symbol	Unit	min	typ	max
Resistance	R _{ESD}	kΩ		1	



Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			4000	

T _c = 25° C			



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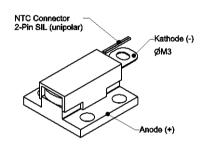
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I -	rac)ime	ne	ns

Parameter	Symbol	Unit	min	typ	max
Emission Plane	h _{EP}	mm	7.75	7.85	7.95
CDL Package Footprint	wxl	mm x mm		25 x 25	

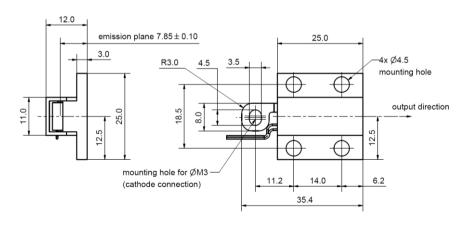
Measurement Conditions / Comments				

Package Pinout

Cathode (-)	Cable
Anode (+)	Housing
NTC	NTC Connector



Package Drawings



Z11-SPEC-CDL02-BAL-0000



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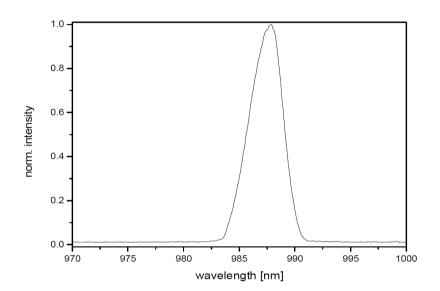
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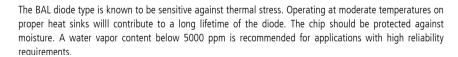
Typical Measurement Results



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

